

recognized by one skilled in the art, such as, but not limited to, SDRAM or RAMBUS, hosting a plurality of memories, such as a DRAM.

[0004] In a typical north bridge processing system, if the received physical address corresponds to the AGP address space, the north bridge further translates the physical address, using a GART table, into a corresponding physical address. Having obtained the physical address, the north bridge communicates with the memory to retrieve the appropriate memory block (e.g., line of memory, or multiple lines of memory where a line is 32 bits, 64 bits, 128 bits, etc.). If the physical address corresponds to the memory, the north bridge utilizes the physical address to facilitate the memory transaction. As such, if the memory transaction was a read transaction, the north bridge facilitates the retrieval of the corresponding memory line or lines from memory and provides them to the central processing unit. If the received physical address corresponds with the PCI address space, the north bridge passes the transaction to the PCI bus.

[0005] A south bridge, upon receiving a physical address, determines which of the plurality of I/O devices is to receive the transaction. To facilitate the forwarding of transactions to the I/O devices, the south bridge includes a plurality of memories, one for each I/O device coupled thereto, for queuing transactions to and from the corresponding I/O device. If an I/O device has a transaction queued, the south bridge, in a Round Robin manner, divides the PCI bus for transporting the queued transaction to the corresponding I/O device. As such, each I/O device has separate memory and therefore does not provide a dynamic interface.

[0006] In addition to the north bridge receiving transactions from the central processing unit, it may also receive transactions from the video graphics processor and the south bridge relaying transactions from I/O devices. Such transactions have varying requirements. For example, transactions from the central processing unit and video graphics processor are typically high-speed transactions which require low latency. The amount of data in such transactions may vary but is generally a memory line or plurality of memory lines per transaction. The transactions from the I/O devices are generally large amounts of data (i.e., significantly more than several memory lines of data), but are typically latency tolerant.

[0007] The central processing unit, the north bridge, the video graphics processor, the south bridge, are fabricated as separate integrated circuits. As such, the transmission path from the central processing unit through the north bridge to the memory is of a relatively significant length, in comparison to buses within the integrated circuits. As is known in the art, the length of a physical path impacts the speed at which data may be transmitted. Such restrictions arise due to the inductance and capacitance of such transmission paths. In short, the relatively substantial lengths of these paths limit the bandwidth capabilities and overall speed capabilities of processing transactions.

[0008] Within such a system, the memory includes a memory, such as but not limited to, a dynamic random access memory (DRAM), which is accessed via a single memory bus. If the system requires additional parallel memory, the system employs additional DRAMs and an addition memory bus. But with each additional DRAM bus, the north bridge requires an additional memory controller. Moreover, the north bridge would require a larger overall substrate package to accommodate parallel memory channels. For example, if the system includes four DRAM buses, the north bridge includes four memory controllers. In addition, each device coupled to the north bridge needs to know which DRAM it is accessing such that it provides the appropriate address in the read and/or write transaction.

[0009] As illustrated in prior art FIG. 1, the north bridge 100 is electrically coupled to the DIMM 102 via a plurality of external connections 104 to a bus 106, wherein the DIMM 102 connects to the bus 106 across a plurality of pin connections (not shown). The DIMM 102 includes a plurality of memories 108, such as RAM or DRAM, connected to the bus 106 for receiving and transmitting system information across the north bridge 100. The north bridge 100 and the DIMM 102 are connected via the external connections 104 and the bus 106, which produce a plurality of complications. For example, during the manufacturing process, there are additional manufacturing steps associated with the external connections. There are also problems of potential interference or corruption of the data transmitted across the connections 104. Moreover, problems arise due to space restrictions within modern computing systems as the DIMM 102 consumes valuable real estate within a computer processing system. And, among other things, having the DIMM 102 externally connected to the north bridge 100 reduces overall system speed as the system information must be

[0010] With further developments of memory devices, a previous approach to reducing problems associated with external placement of memory was to place a frame buffer associated with a graphics processor on a north bridge integrated circuit for storing graphics information. This previous approach teaches solely of a graphics memory buffer for interaction with the graphics processor, but does not address complications that arise with respect to system instructions. Moreover, the frame buffer consisted of a memory storage size, in bytes which is wholly inadequate for modern processing requirements, which would render it almost useless for storing system instructions. Moreover, the previous approach would be unable to include adequate system memory without thereupon producing an extremely large integrated circuit, inconsistent with a standard dimension integrated circuit, which would be practically unusable in modern computing systems due to the size of the memory devices at that time.

[0011] Therefore, there exists a need for an improved integrated circuit having including at least one system memory integrated with the information router for the improved processing of system information and to provide dual channel bandwidth with a single channel package size.

[0012] The invention will be more readily understood with reference to the following drawings, wherein:

[0013] FIG. 1 is a block diagram illustrating a prior art memory and north bridge system;

[0014] FIG. 2 is a block diagram of a computing system in accordance with one embodiment of the present invention;

[0015] FIG. 3 is a perspective view of a top side of an integrated circuit in accordance with one embodiment of the present invention;

[0016] FIG. 4 is a perspective view of a bottom side of the integrated circuit of FIG. 3;

- [0017] FIG. 5 is a perspective view of an alternative embodiment of the top side of the integrated circuit in relation to a printed circuit board
- [0018] ;FIG. 6 is a cross-sectional view of FIG. 5 across line V-V
- [0019] ;FIG. 7a is a perspective view of an alternative embodiment of the top side of the integrated circuit;
- [0020] FIG. 7b is a perspective view of an alternative embodiment of the bottom side of the integrated circuit;
- [0021] FIG. 8 is a flowchart illustrating the step for making the integrated circuit in accordance with one embodiment of the present invention; and
- [0022] FIG. 9 is a block diagram of a computer processing system in accordance with another embodiment of the present invention.

Detailed Description

- [0023] Generally, an integrated circuit having memory disposed thereon includes a standard dimension carrier substrate. An information router, such as a north bridge, a south bridge, or any other integrated circuit capable of receiving and routing information between multiple locations, is integrated on the carrier substrate. The integrated circuit further includes system memory also integrated on the carrier substrate. The system memory is within electrical communication with the information router across a plurality of electrical leads associated with the carrier substrate, such as disposed within multiple layers on the substrate or disposed on an outer surface of the substrate. Thus, system instructions may be stored and retrieved from the system memory through the information router, all within the standard dimension carrier substrate.
- [0024] More specifically, FIG. 2 illustrates a processing system 200 having a central processing unit (CPU) 202 in communication with an integrated circuit 204 in accordance with one embodiment of the present invention. The integrated circuit 204 includes an information router 206, such as a north bridge, south bridge, or any other integrated circuit capable of receiving and routing data between multiple locations, and a system memory 208 such as a RAM, chip scale package memory (CSP) having a

memory die disposed therein, or any other suitable memory device as recognized by one having ordinary skill in the art.

[0025] The system 200 further includes a cache 212 coupled to the CPU 202 and a video graphics processor 214 and a south bridge 216 coupled to the integrated circuit 204. Moreover, the system 200 includes a plurality of input/output (I/O) devices 218, 220 and 222 coupled to the south bridge 216.

[0026] Typically, the CPU 202 may receive instructions 224 from the cache 202, process the instructions and provide processing instructions 226 to the information router 206. The information router 206 uses known data routing techniques, such as the processing technique of a north bridge utilizing a look aside table to route the processing instructions 226 to the appropriate location. If the processing instructions 226 include storing or retrieving system instructions 228, the information router 204 provides or retrieves the system instructions 228 from the system memory 208 within the same integrated circuit 204. With the information router 206 and the system memory 208 being disposed on the same integrated circuit 204, system instructions 228 are stored or retrieved from the system memory, 208, thereby improving the processing speed of the integrated circuit 204.

[0027] In the event the processing instructions 226 include graphics processing instructions 230, the information router may provide these instructions 230 to the video graphics processor 214. Furthermore, if the processing instructions include input or output instructions 232, the information router 204 provides these instructions to the south bridge 216 whereupon the south bridge provides an input or output signal 234 to at least one of the input/output devices 218, 220, and 222.

[0028] FIG. 3 illustrates a perspective view of one embodiment of the integrated circuit 204. The integrated circuit 204 includes a carrier substrate 240 having a top surface 242. The carrier substrate 240 is composed of Bismaleimide Triazine (BT Laminate) but may also be composed of a ceramic, flex or any other suitable material as recognized by one skilled in the art. Furthermore, the carrier substrate has a standard dimension capable of being readily manufactured and utilized in conjunction with a typical computer system. A standard dimension carrier substrate typically includes a carrier substrate having a dimension of a width between 31 and 41 millimeters and a

length between 31 and 41 millimeters, more specifically in the preferred embodiment, the carrier substrate has a dimension of approximately 31 by 31 millimeters or 34 by 34 millimeters. As recognized by one skilled in the art, other dimension carrier substrates may be utilized wherein the standard dimension includes any dimension commercially available and compatible with the space restrictions within a computing system.

[0029] Moreover, the carrier substrate 240 may have a plurality of layers 244, wherein each of the layers includes a plurality of electrical leads 246, shown in shadow on the top surface 242. As recognized by one having ordinary skill in the art, the number of layers 244 allows for the placement of varying amounts of electrical leads within the carrier substrate 240. Different carrier substrates 240 having different numbers of layers 244 may be utilized, wherein the carrier substrate 240 provides the electrical coupling of elements attached thereto.

[0030] FIG. 3 further illustrates a plurality of chip scale package (CSP) system memories 248 disposed on the top surface 242. The system memories 248 are electrically coupled to corresponding electrical leads within the carrier substrate 240. In one embodiment, the plurality of memories 248 are attached to the electrical leads 246 using a solder technique to produce a plurality of solder joints for conducting electrical communication. As recognized by one skilled in the art, any other connection technique may be utilized to attach the system memories 248 to the electrical leads 246, such as wirebonding. Also illustrated in FIG. 3, the integrated circuit 204 further includes a heat sink attached to the carrier substrate 240 using an epoxy.

[0031] FIG. 4 illustrates, in perspective view, a bottom surface 252 of the integrated circuit having an application specific integrated circuit (ASIC) 254 and a solder ball array 256 composed of a plurality of solder members 258, such as solder balls, disposed thereon. In one embodiment, the application specific integrated circuit 254 is an ASIC die having data routing functionality, such as a north bridge. In one embodiment, the solder ball array is in accordance with copending United States Patent Application having attorney docket no. 00100.02.0042 entitled SOLDER BALL COLLAPSE CONTROL APPARATUS AND METHOD THEREOF and a filing date of XXX, XX,

2002. As recognized by one having ordinary skill in the art, any solder ball array 256 may be disposed on the bottom surface 252 such that the electrical leads (not shown) within the carrier substrate 204 may be in electrical contact with another surface after the solder balls have been melted.

[0032] The ASIC 254 is in electrical communication with the plurality of memories 248 of FIG. 3 through the electrical leads 246, whereupon system instructions (228 of FIG. 2) may be stored and retrieved from the system memory 248 through the ASIC 254.

[0033] FIG. 5 illustrates another embodiment of the present invention having a carrier substrate 260 having a plurality of system memories 262 and a heat sink 264 disposed on a top surface 266. The carrier substrate 260 is disposed on top of a printed circuit board 268. Furthermore, in one embodiment, the bottom surface of carrier substrate (not visible) is illustrated by FIG. 3, having the ASIC 254 and the solder ball array 256 disposed thereon.

[0034] The printed circuit board 268 includes a plurality of electrical contacts such that when a heat is applied to the combination of the printed circuit board 268 and the carrier substrate 260, the solder ball array creates a plurality of solder joints that allow electrical communication therebetween.

[0035] To provide further clarification, FIG. 6 illustrates a cross-sectional view of the carrier substrate 260 and the printed circuit board along the cross-section VI-VI. As illustrated, in one embodiment the ASIC 256 is disposed on and extending out from the bottom surface 252. The solder ball array 256 engages the printed circuit board 268, and is thereupon electrically coupled through a plurality of solder joints formed by the solder balls 258 of the solder ball array 256.

[0036] Moreover, FIG. 6 illustrates the system CSP memory 262 affixable to the top surface 240 of the carrier substrate using a plurality of solder balls 270. Similar to the solder ball array 256 on the bottom surface 252, the solder balls 270 provide for a plurality of solder joints between the CSP system memory 262 and the carrier substrate 260, more specifically to the electrical leads 246 within the carrier substrate 260.

[0037] Further illustrated in the cross-sectional view of FIG. 6 is the connection of the

ASIC 254 to the carrier substrate 260. In one embodiment, the ASIC is an ASIC die that is connected to the carrier substrate 260, more specifically to the electrical leads 246, using known flip chip technology. Thereupon, electrical communication occurs between the system memories 262 and the ASIC 254 across the electrical leads 246, within the same integrated circuit 204.

[0038] FIG. 7a illustrates another embodiment of the integrated circuit 204 of the present invention wherein the system memories 274 are memory dies attached to the carrier substrate 260 using a plurality of wirebonds 276. More specifically, the memory dies are attached to the electrical leads 246 which are coupled to the ASIC (not visible in FIG. 7a) disposed on the bottom surface 252 of the carrier substrate 260. Further illustrated in FIG. 7a is the heat sink 264 on the top surface, which provides protection for the ASIC 254 and the system memories 274 when heat is applied to melt the solder ball array in accordance with known heat sink operations.

[0039] FIG. 7b illustrates another embodiment of the integrated circuit 204 of the present invention wherein the data router is an ASIC die 280 coupled to the bottom surface 252 of the carrier substrate 260 using a plurality of wirebonds 282. Similar to the embodiment of FIG. 7a, the wirebonds 282 provide electrical communication between the ASIC die 280 and the memories, not visible, disposed on the top surface of the carrier substrate 260.

[0040] FIG. 8 illustrates the steps of a method for making the integrated circuit 204 in accordance with one embodiment of the present invention. The method begins 300 by coupling system memory 248 or 274 to the top surface 242 of the carrier substrate 240, designated at step 302. Depending on the type of system memory used, such as either the CSP memory 248 or the memory die 274, the system memory is coupled to the carrier substrate differently, step 304. If the system memory is CSP memory 248, the system memory 248 may be soldered to the carrier substrate 260, step 306. In another embodiment, if the memory is the memory die 274, the memory die 274 is attached using a plurality of wirebonds 276, step 308. More specifically, when the system memory 248 or 274 is attached to the carrier substrate 260, the memory 248 or 274 is attached to the plurality of electrical leads 246 associated with the carrier substrate 260.

described herein. For example, the ASIC die may contain further integrated circuits for further functionality and the memories disposed on the carrier substrate may provide for storage and retrieval of more than system information and graphics information. It is therefore contemplated to cover by the present invention any and all modifications, variations or equivalents that fall within the spirit and scope of the basic underlying principles disclosed and claimed herein.